

U16C30 Thru U16C60

Switchmode Dual Ultrafast Power Rectifiers

-- Designed for use in switching power supplies inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- * High Surge Capacity
- *Low Power Loss, High efficiency
- * Glass Passivated chip junctions
- *175 ^OC Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- * High-Switching Speed 50 Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O
- * Pb free

* In compliance with EU RoHs directives



MAXIMUM RATINGS

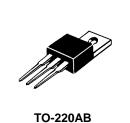
Characteristic	Symbol		Unit			
Characteristic		30	40	50	60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	300	400	500	600	V
RMS Reverse Voltage	V _{R(RMS)}	210	280	350	420	V
Average Rectifier Forward Current Per Leg $T_C=125^{\circ}C$ Per Total Device	I _{F(AV)}			3.0 16		A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	125			A	
Operating and Storage Junction Temperature Range	T _J , T _{stg}		-65 te	o +175		°C

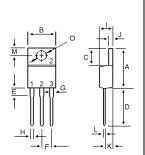
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	U16C				Unit
Characteristic	Symbol	30	40	50	60	Unit
Maximum Instantaneous Forward Voltage ($I_F = 8.0 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 8.0 \text{ Amp } T_C = 100^{\circ}C$)	V _F	1.30 1.12		1.50 1.34		v
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R	10 300			uA	
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0,I _{rr} =0.25 A)	Trr	50			ns	
Typical Thermal Resistance junction to case	R _{θ j-c}	3.5			°C/w	
Typical Thermal Resistance junction to ambinent	R _{θ j-A}	65			k/w	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P	1	85	7	0	РF

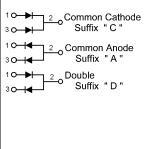


16 AMPERES 300-600 VOLTS





DIM	MILLIMETERS			
	MIN	MAX		
Α	14.68	16.00		
В	9.78	10.42		
С	5.02	6.60		
D	13.00	14.62		
Е	3.10	4.19		
F	2.41	2.67		
G	1.10	1.67		
Н	0.69	1.01		
I	3.21	4.98		
J	1.14	1.40		
К	2.20	3.30		
L	0.28	0.61		
Μ	2.48	3.00		
0	3.50	4.00		





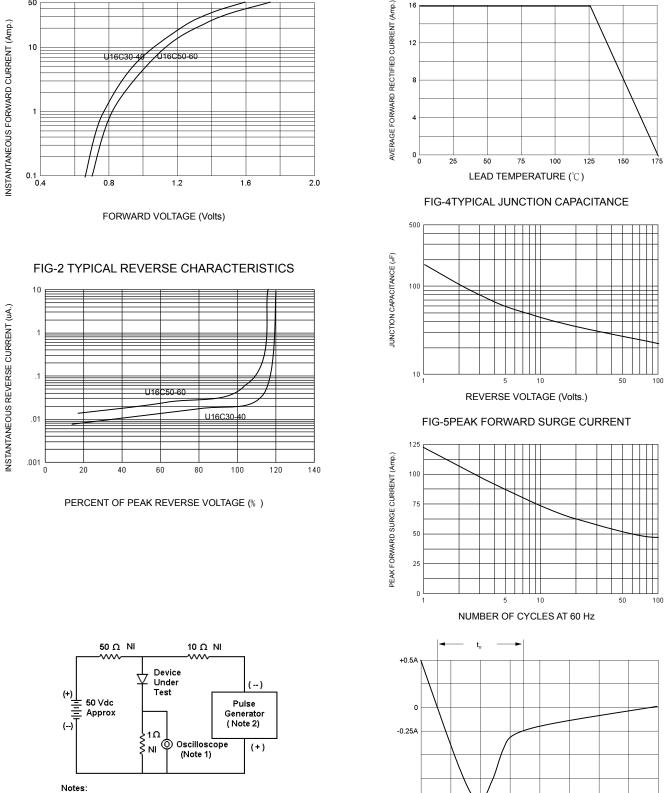
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FIG-1 TYPICAL FORWARD CHARACTERISTICS

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FIG-3 FORWARD CURRENT DERATING CURVE

16



1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

-1.0A



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